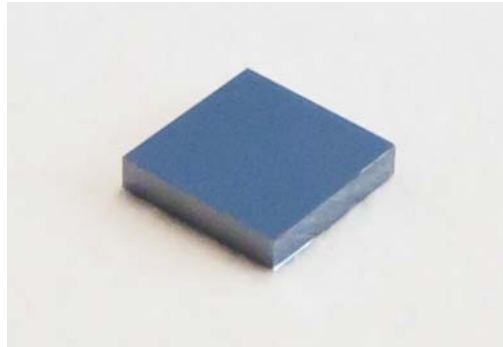


B-M-1030nm-1.3x1.3**Bragg mirror 1030 nm with chip area 1.3 mm x 1.3 mm on GaAs**

Material:	AlAs/GaAs epitaxial Bragg mirror on single crystalline GaAs substrate
Chip area	1.3 mm x 1.3 mm; other dimensions on request
Chip thickness	450 μm

Spectral reflectance